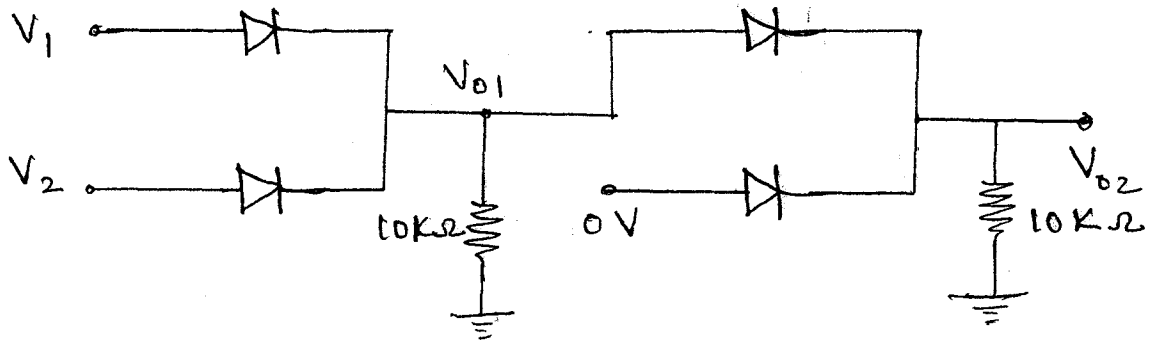
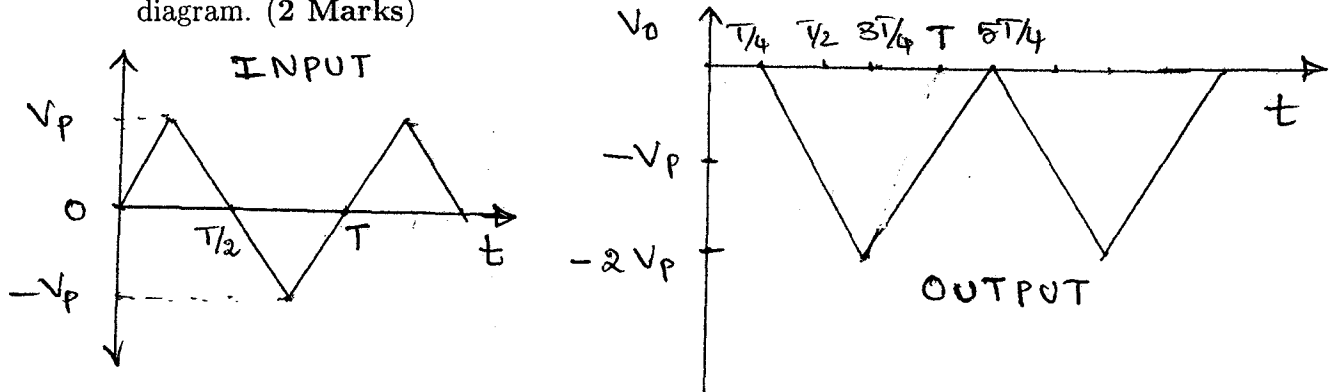


*Answer all the questions. Total no. of pages: 2.*

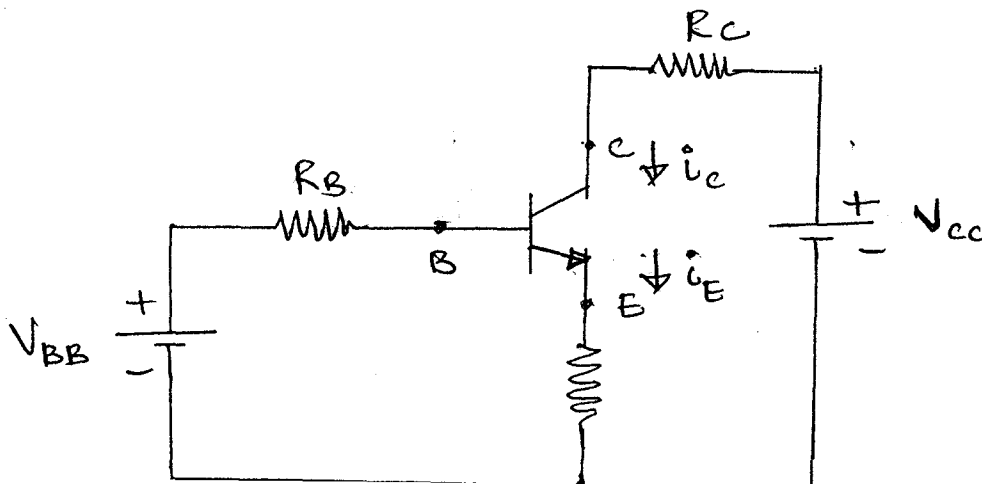
- Derive ripple factor for a half-wave rectifier. (2 Marks)
  - Draw the circuit diagram of a passive band-stop filter, derive its voltage transfer function and also plot its frequency response. (3 Marks)
- For the circuit shown below, find  $V_{o1}$  and  $V_{o2}$  when (i)  $V_1 = V_2 = 0V$ , (ii)  $V_1 = 5V$  and  $V_2 = 0V$ , (iii)  $V_1 = V_2 = 5V$ . Assume that  $V_\gamma = 0.6V$ . (3 Marks)



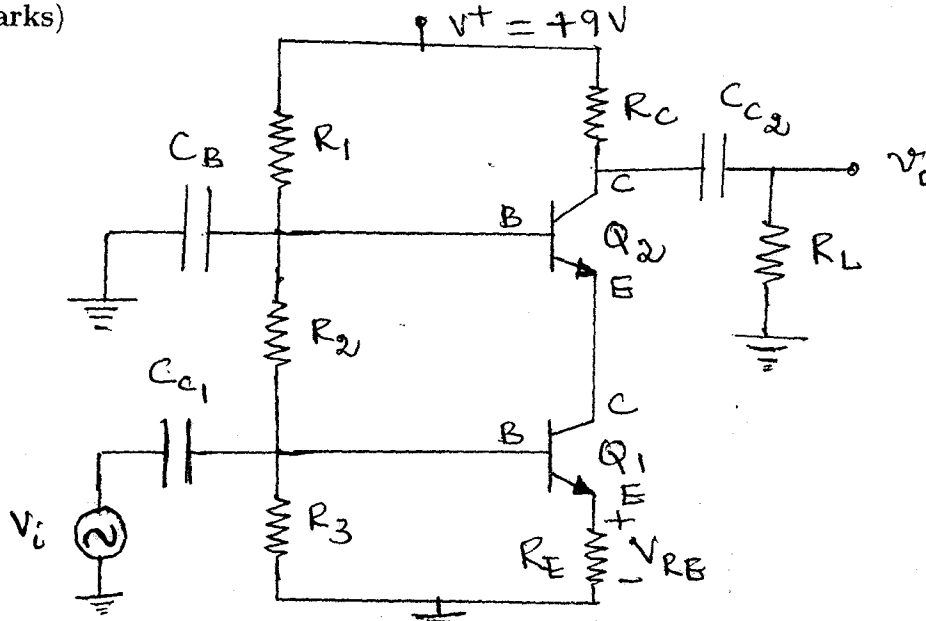
- The input and output waveforms are shown in Fig. for a circuit. Draw that circuit diagram. (2 Marks)



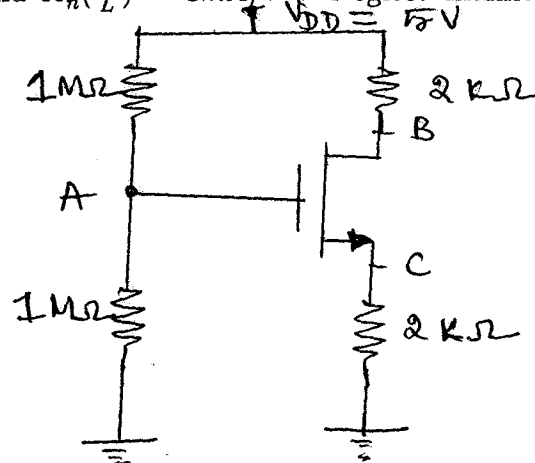
- The transistor shown below is a silicon device with a base current of  $40 \mu A$  and  $I_{CBO} = 0$ . If  $V_{BB} = 6V$ ,  $R_E = 1k\Omega$ , and  $\beta = 80$ , find (i)  $I_{EQ}$  and (ii)  $R_B$  (iii) If  $V_{CC} = 15V$  and  $R_C = 3k\Omega$ , find  $V_{CEQ}$ . (5 Marks)



4. Design circuit shown in Fig., called a cascade circuit, to meet the following specifications:  $V_{CE1} = V_{CE2} = 2.5V$ ,  $V_{RE} = 0.7V$ ,  $I_{C1} \cong I_{C2} = 1mA$ , and  $I_{R1} \cong I_{R2} \cong I_{R3} = 0.1mA$ . (5 Marks)



5. Determine the voltages at all nodes and the current through all branches in Fig. below. Assuming  $V_T = 1V$  and  $K'_n(\frac{W}{L}) = 1mA/V^2$ . Neglect channel length modulation. (5 Marks)



6. Design the biasing of the NMOS cascade circuit to meet specific requirements. For the circuit shown below, the transistor parameters are:  $V_{TN1} = V_{TN2} = 1.2V$ ,  $K_{n1} = K_{n2} = 0.8mA/V^2$ , and  $\lambda_1 = \lambda_2 = 0$ . Let  $R_1 + R_2 + R_3 = 300k\Omega$  and  $R_5 = 10k\Omega$ . Design the circuit such that  $I_{DQ} = 0.4mA$  and  $V_{DSQ1} = V_{DSQ2} = 2.5V$ . (5 Marks)

